Taiwan Semiconductor

16A, 200V - 600V Ultra Fast Rectifier

FEATURES

- AEC-Q101 qualified available
- Ultra fast recovery times
- 175°C operating junction temperature
- Popular TO-220AB Package
- High temperature glass passivated junction
- High voltage capability to 600 volts
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- DC to DC converters
- Switching mode converters and inverters
- Freewheeling application

MECHANICAL DATA

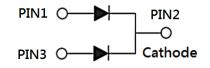
- Case: TO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.82g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I _F	16	А
V _{RRM}	200 - 600	V
I _{FSM}	100	А
T _{J MAX}	175	°C
Package	TO-220	DAB
Configuration	Dual d	lies





TO-220AB



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	MUR1620CT	MUR1640CT	MUR1660CT	UNIT
Marking code on the device		MUR1620CT	MUR1640CT	MUR1660CT	
Repetitive peak reverse voltage	V _{RRM}	200	400	600	V
Reverse voltage, total rms value	V _{R(RMS)}	140	280	420	V
Forward current	I _F		16		А
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}		100		А
Junction temperature	TJ		-55 to +175		°C
Storage temperature	T _{STG}		-55 to +175		°C



THERMAL PERFORMANCE				
PARAMETER		SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	MUR1620CT	$R_{\Theta JC}$	3	°C/W
Junction-to-case thermal resistance	MUR1640CT MUR1660CT	$R_{\Theta JC}$	2	°C/W

ELECTRICAL SPEC	IFICATIONS	$T_A = 25^{\circ}C$ unless other	erwise noted)			
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage per diode ⁽¹⁾	MUR1620CT		V _F	-	0.975	V
	MUR1640CT	I _F = 8A, T _J = 25°C		-	1.300	V
	MUR1660CT			-	1.500	V
	MUR1620CT			-	0.895	V
	MUR1640CT	I _F = 8A, T _J = 150°C		-	1.100	V
	MUR1660CT			-	1.200	V
Reverse current @ rated V_R per diode ⁽²⁾	MUR1620CT	T _J = 25°C	I _R	-	5	μA
	MUR1640CT MUR1660CT			-	10	μA
	MUR1620CT	T _J = 125°C		-	250	μA
	MUR1640CT MUR1660CT			-	500	μA
Reverse recovery time	MUR1620CT	$I_F = 0.5A, I_R = 1.0A,$ $I_{rr} = 0.25A$		-	25	ns
	MUR1640CT MUR1660CT		t _{rr}	-	50	ns

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
MUR16xCT	TO-220AB	50 / Tube
MUR16xCTH	TO-220AB	50 / Tube

Notes:

1. "x" defines voltage from 200V(MUR1620CT) to 600V(MUR1660CT)

2. "H" means AEC-Q101 qualified



INSTANTANEOUS REVERSE CURRENT (µA)

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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

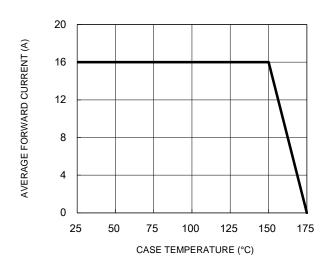


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

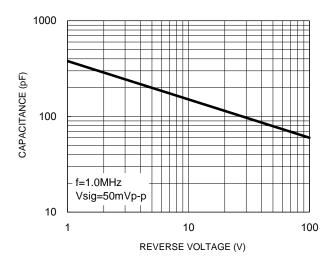
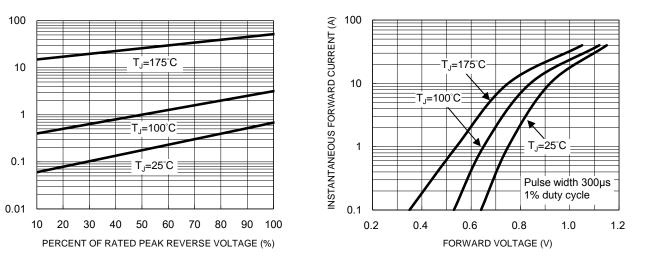


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



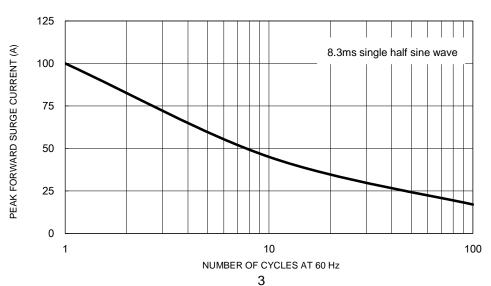


Fig.5 Maximum Non-Repetitive Forward Surge Current

Version: I2104



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

50Ω 10Ω - trr 🗕 NONINDUCTIVE NONINDUCTIVE ~~~ ~~~ +0.5A (-) ± DUT • (+) 50Vdc PULSE 0 GENERATOR = (approx) -0.25A (NOTE 2) (-) IΩ OSCILLOSCOPE 6 (+) (NOTE 1) -1.0A NOTES: 1. Rise Time=7ns max. Input Impedance= ≐ 1 megohm 22pf 2. Rise Time=10ns max. Sourse Impedance= 50 ohms

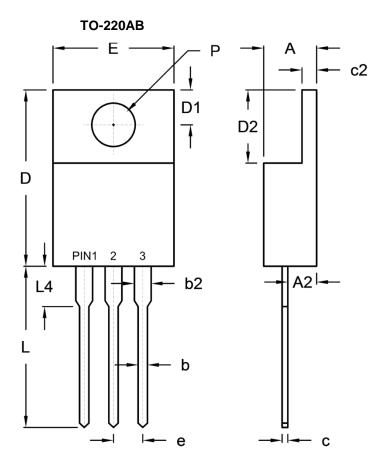
Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



MUR1620CT – MUR1660CT

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PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit ((inch)
	Min.	Max.	Min.	Max.
A	4.42	4.76	0.174	0.187
A2	2.20	2.80	0.087	0.110
b	0.68	0.94	0.027	0.037
b2	1.14	1.77	0.045	0.070
с	0.35	0.64	0.014	0.025
c2	1.14	1.40	0.045	0.055
D	14.60	16.00	0.575	0.630
D1	2.62	3.44	0.103	0.135
D2	5.84	6.86	0.230	0.270
E	-	10.50	-	0.413
е	2.41	2.67	0.095	0.105
L	13.19	14.79	0.519	0.582
L4	2.80	4.20	0.110	0.165
Р	3.54	4.00	0.139	0.157

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



MUR1620CT – MUR1660CT

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